

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Appl. No. : 10/811,107  
Applicant : Hironobu FUKUI  
Filed : March 26, 2004  
TC/A.U. : 2822  
Examiner : LEWIS, Monica

Confirmation No. 9214

Atty Docket No. : 351991-992050  
Customer No. : 26379

Title: METAL OXIDE SEMICONDUCTOR (MOS) TYPE SEMICONDUCTOR  
DEVICE AND MANUFACTURING METHOD THEREOF

**AMENDMENT AND RESPONSE TO OFFICE ACTION**

M/S: AMENDMENT  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

In reply to the Office Action of August 24, 2007, please enter the amendments set forth below and consider the following remarks:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims that begins on page 3 of this paper.

**Remarks** begin on page 5 of this paper.